SENSITRON SEMICONDUCTOR

SS5550/US
SS5551/US
SS5552/US
SS5553/US
SS5554/US

TECHNICAL DATA
DATA SHEET 5108, REV -

HIGH CURRENT AXIAL LEAD RECTIFIERS

DESCRIPTION: 200-1000 VOLT, 3.0 AMP, 2000 NANOSECOND RECTIFIER

-Suffix "US" denotes melf/surface mount packaging

MAX. RATINGS / ELECTRICAL CHARACTERISTICS All ratings are at $T_A = 25^oC$ unless otherwise specified.

RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Inverse Voltage (PIV) **1N5550** **1N5551** **1N5552** **1N5553** **1N5554**	-	-	-	 200 400 600 800 1000	Vdc
Average DC Output Current (I_o)	$T_A = +55^oC$	-	-	3.0	Amps
Peak Single Cycle Surge Current (I_{fsm})	t_p = 8.3 ms Single Half Cycle Sine Wave, Superimposed On Rated Load	-	-	100	Amps(pk)
Operating and Storage Temp. (T_{op} & T_{stg})	-	-65	-	+175	°C
Maximum Forward Voltage (V_f) **1N5550** **1N5551** **1N5552** **1N5553** **1N5554**	I_f = 9.0A (300 µsec pulse, duty cycle < 2%)	-	-	 1.2 1.2 1.2 1.3 1.3	Volts
Maximum Instantaneous Reverse Current At Rated (PIV)	$T_A = 25°$ C $T_A = 100°$ C	-	-	1.0 60	µAmps
Reverse Recovery Time (t_{rr})	I_f = 0.5A, I_r = 1.0A, I_{rr} = 0.25A	-	-	2000	nsec
Thermal Resistance (θ_{JL})	Junction to Lead d = 0.375"			22	°C/W
Thermal Resistance (θ_{JEC})	Junction to Endcap	-	-	6.5	° C/W

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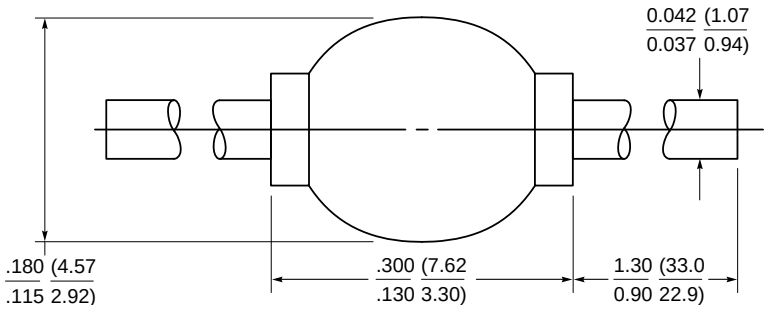
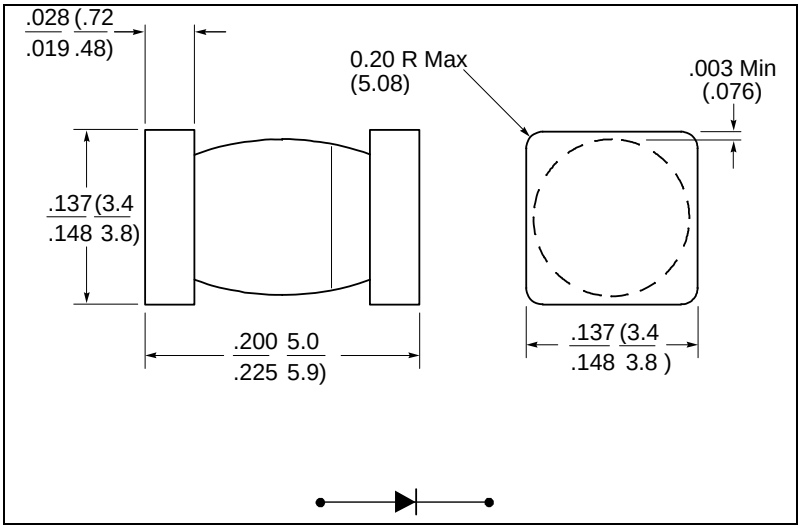
MECHANICAL DIMENSIONS In Inches / (mm), min./max.



PKG. 301

Note: The cathode side is marked with a dark colored band on one side of the diode body.



MELF-B

Note: The cathode side is marked on body with a dark band.

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TECHNICAL DATA
DATA SHEET 126, REV G

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